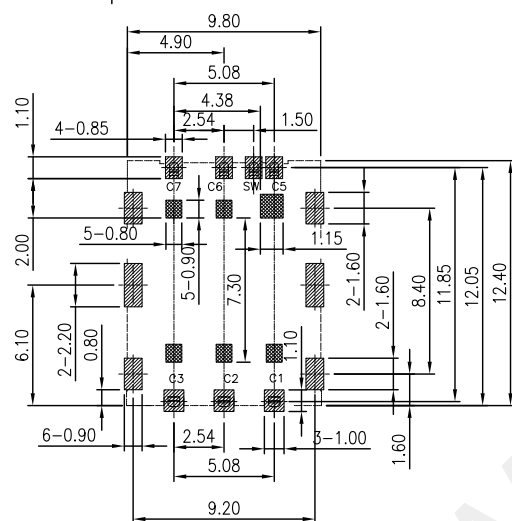
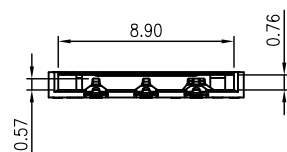
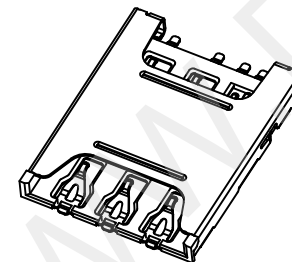
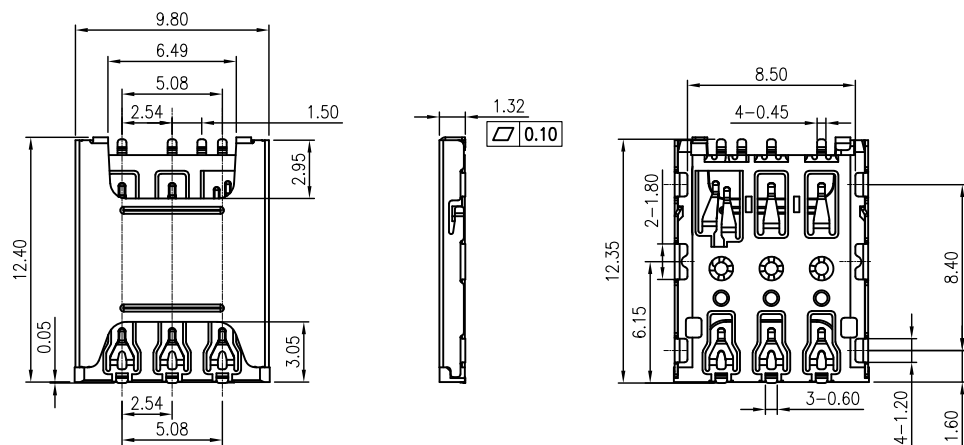
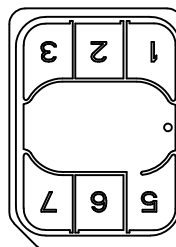


RECOMMENDED P.C.B LAYOUT COMPONENT SIDE (TOLERANCE ± 0.05)

Nano SIM Circuit Description:

PIN No.	FUNCTION
C1	VCC
C2	RST
C3	CLK
C5	GND
C6	VPP
C7	I/O



TECHNICAL CHARACTERISTICS1.

1.General Characteristics

Dimensions:12.40LX9.80WX1.35H mm

Weight: Approx 0.50±0.2g

Durability:1,500cycles min.

2. Electrical Characteristics

Contact resistance: 50mΩ typical,

100m. max

Insulation resistance: >1000MΩ/500V DC

Solderability

Vaporphase:215°C,30sec.MaxIR

reflow:250C,5sec.MaxManual soldering:370'C,3sec.Max

4.Environmental Characteristics

Operating temperature: $-40^{\circ}\text{C} \sim +85^{\circ}\text{C}$

Operating humidity: 10%~+95%RH

3	CONTACT	1	COPPER ALLOY	CONTACT AREA:GOLD PLATED
2	SHELL	1	STAINLESS STEEL	
1	HOUSING	1	LCP UL94V-0	COLOR:BLACK
NO.	DESCRIPTION	Q'TY	Material	Finish



深圳市华宇创精密电子有限公司

TOLERANCE:		DRAWN BY : 陈一鸣	DATE : 2014-02-23	PART NAME:	
X.X ±0.30 X.XX ±0.25 X.XXX ±0.15 X.* ±2* X.X* ±0.5*				NANO SIM 6P 1.32H 带检测P	
		CHECKED BY:	DATE :	PART NO.	HYC386-SIM07-132
		马跃	2014-02-23	MOLD NO.	
UNIT: mm [inch]		APPROVED BY:	DATE :	DRAW NO:	HYC-2602281131
SCALE:1:1	SIZE: A4	邱敏	2014-02-23	SHEET NO.	1 OF 1